Electronic Supplementary Information (ESI)

Electronic and optical properties of a novel fluoroaluminate red phosphor $Cs_2NaAl_3F_{12}$:Mn⁴⁺ with high color purity for white light-emitting diodes

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Figure S1. The corresponding selected area for EDS measurement from $Cs_2NaAl_3F_{12}$:2.33%Mn⁴⁺ product.



Figure S2. TG curve of the prepared $Cs_2NaAl_3F_{12}$: 2.33% Mn^{4+} product.



Figure S3. CIE chromaticity diagram for the WLEDs made of (c) YAG and (d) $YAG-Cs_2NaAl_3F_{12}:2.33\%Mn^{4+}$ mixture on GaN chip.

Table S1. Performance of the GaN-based WLEDs fabricated from (c) YAG and (d)

No. of devices	CIE (x, y)	CCT (K)	CRI (K)	LE (lm/W)
с	0.3172, 0.3470	6177	77.3	176.11
d	0.3947, 0.4066	3856	88.7	78.91

 $YAG\text{-}Cs_2NaAl_3F_{12}\text{:}2.33\% Mn^{4+} \text{ mixture at } 20 \text{ mA drive current.}$